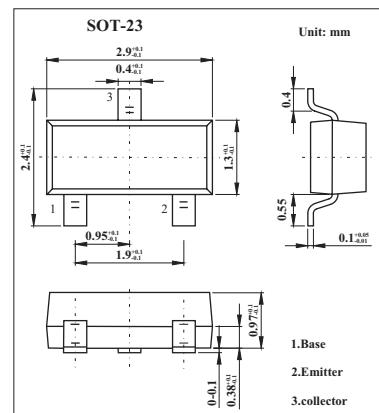


## PNP High-Voltage Transistors

### BSR20, BSR20A

#### ■ Features

- Low current (max. 300 mA)
- High voltage (max. 150 V).



#### ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage BSR20 BSR20A	V <sub>CBO</sub>	-130	V
		-160	V
Collector-emitter voltage BSR20 BSR20A	V <sub>CEO</sub>	-120	V
		-150	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	I <sub>C</sub>	-300	mA
Peak collector current	I <sub>CM</sub>	-600	mA
Base current	I <sub>B</sub>	-100	mA
Total power dissipation *	P <sub>tot</sub>	250	mW
Storage temperature	T <sub>stg</sub>	-65 to +150	°C
Junction temperature	T <sub>j</sub>	150	°C
Operating ambient temperature	T <sub>amb</sub>	-65 to +150	°C
Thermal resistance from junction to ambient *	R <sub>th j-a</sub>	500	K/W

\* Transistor mounted on an FR4 printed-circuit board.

**BSR20, BSR20A**■ Electrical Characteristics  $T_a = 25^\circ\text{C}$ 

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector cutoff current BSR20	I <sub>CBO</sub>	I <sub>E</sub> = 0; V <sub>CB</sub> = -100 V			-100	nA
		I <sub>E</sub> = 0; V <sub>CB</sub> = -100 V; T <sub>amb</sub> = 100 °C			-100	µA
Collector cutoff current BSR20A	I <sub>CBO</sub>	I <sub>E</sub> = 0; V <sub>CB</sub> = -120 V			-50	nA
		I <sub>E</sub> = 0; V <sub>CB</sub> = -120 V; T <sub>amb</sub> = 100 °C			-50	µA
Emitter cutoff current	I <sub>EBO</sub>	I <sub>C</sub> = 0; V <sub>EB</sub> = -4 V			-50	nA
DC current gain BSR20 BSR20A	h <sub>FE</sub>	I <sub>C</sub> = -1 mA; V <sub>CE</sub> = -5 V	30			
			50			
DC current gain BSR20 BSR20A	h <sub>FE</sub>	I <sub>C</sub> = -10 mA; V <sub>CE</sub> = -5 V	40		180	
			60		240	
DC current gain BSR20 BSR20A	h <sub>FE</sub>	I <sub>C</sub> = -50 mA; V <sub>CE</sub> = -5 V	40			
			50			
base-emitter saturation voltage	V <sub>CEsat</sub>	I <sub>C</sub> = -10 mA; I <sub>B</sub> = -1 mA			-200	mV
		I <sub>C</sub> = -50 mA; I <sub>B</sub> = -5 mA			-500	mV
Collector capacitance	C <sub>c</sub>	I <sub>E</sub> = i <sub>e</sub> = 0; V <sub>CB</sub> = -10 V; f = 1 MHz			6	pF
Transition frequency BSR20 BSR20A	f <sub>T</sub>	I <sub>C</sub> = -10 mA; V <sub>CE</sub> = -10 V; f = 100 MHz	100		400	MHz
			100		300	MHz

## ■ hFE Classification

TYPE	BSR20	BSR20A
Marking	T35	T36